

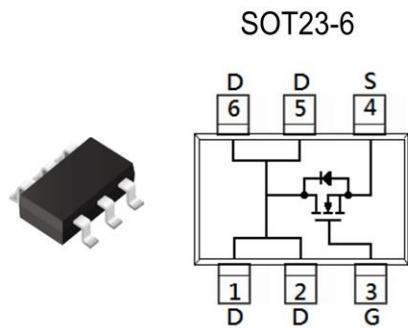
General Features

- $V_{DS}=30V$ $I_D=6A$
- $R_{DS(ON)} < 23m\Omega$, $V_{GS}=10V$,
- $R_{DS(ON)} < 32m\Omega$, $V_{GS}=4.5V$,

Application

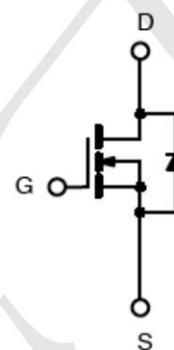
- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

Package and Pin Configuration



Marking Information
 Logo
XXXX: Marking ID

Block Diagram



Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current (Note 4)	I_D	6	A
Pulsed Drain Current (Note 1)	I_{DM}	25	
Power Dissipation Power Dissipation	$T_a=25^\circ C$	2	W
		16	mW/ $^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance - Junction to Ambient (Note 3)	$R_{\theta JA}$	62.5	$^\circ C/W$



TECH PUBLIC
台月电子

STT6N3LLH6
30V N-Channel Enhancement Mode MOSFET

www.sot23.com.tw

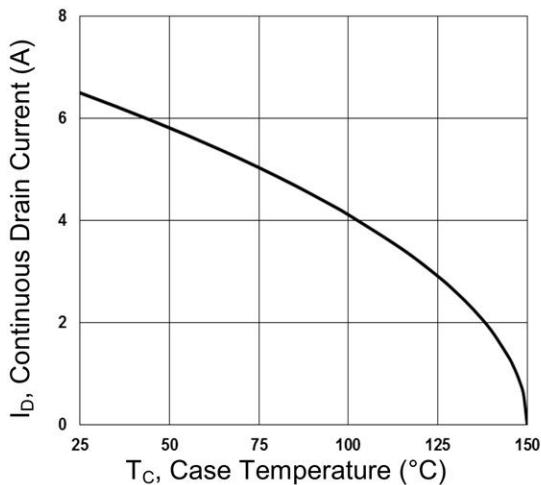
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	30	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 6A$	$R_{DS(on)}$	--	18	23	$m\Omega$
	$V_{GS} = 4.5V, I_D = 4A$		--	22	32	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	1.0	1.5	2.5	V
Zero Gate Voltage Drain Current	$V_{DS} = 30V, V_{GS} = 0V$	I_{DSS}	--	--	1	μA
	$V_{DS} = 24V, T_J = 125^\circ C$		--	--	10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	μA
Forward Transconductance ^(Note 3)	$V_{DS} = 10V, I_D = 4A$	g_{fs}	--	6.5	--	S
Dynamic						
Total Gate Charge ^(Note 3,4)	$V_{DS} = 15V, I_D = 6A, V_{GS} = 4.5V$	Q_g	--	4.1	--	nC
Gate-Source Charge ^(Note 3,4)		Q_{gs}	--	1	--	
Gate-Drain Charge ^(Note 3,4)		Q_{gd}	--	2.1	--	
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	C_{iss}	--	345	--	pF
Output Capacitance		C_{oss}	--	55	--	
Reverse Transfer Capacitance		C_{rss}	--	32	--	
Switching						
Turn-On Delay Time ^(Note 3,4)	$V_{DD} = 15V, I_D = 1A, V_{GS} = 10V, R_G = 6\Omega$	$t_{d(on)}$	--	2.8	--	ns
Turn-On Rise Time ^(Note 3,4)		t_r	--	7.2	--	
Turn-Off Delay Time ^(Note 3,4)		$t_{d(off)}$	--	15.8	--	
Turn-Off Fall Time ^(Note 3,4)		t_f	--	4.6	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	6	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	25	A
Diode-Source Forward Voltage	$V_{GS} = 0V, I_S = 1A$	V_{SD}	--	--	1	V

Note:

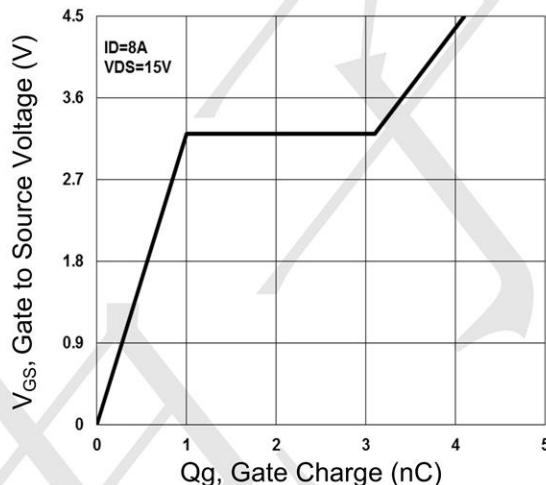
1. Pulse width limited by safe operating area
2. $L = 1mH, I_{AS} = 8A, V_{DD} = 25V, R_G = 25\Omega$, Starting $T_J = 25^\circ C$
3. Pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
4. Switching time is essentially independent of operating temperature.

Typical Electrical and Thermal Characteristics (Curves)

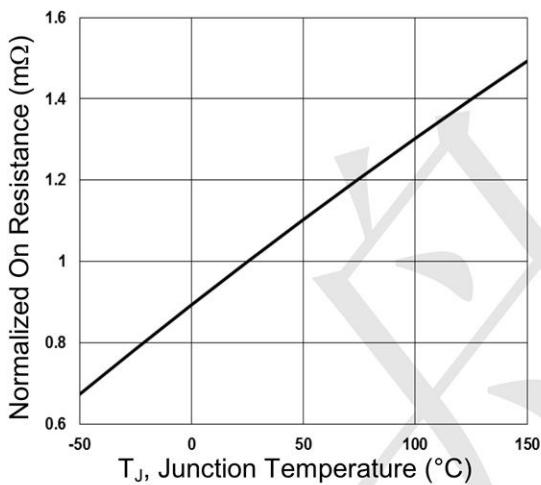
Continuous Drain Current vs. T_C



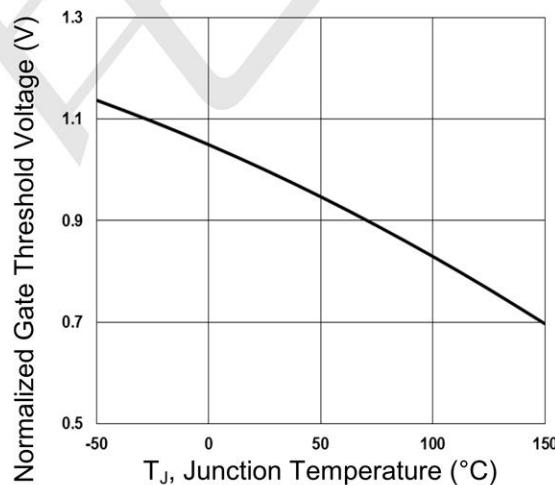
Gate Charge



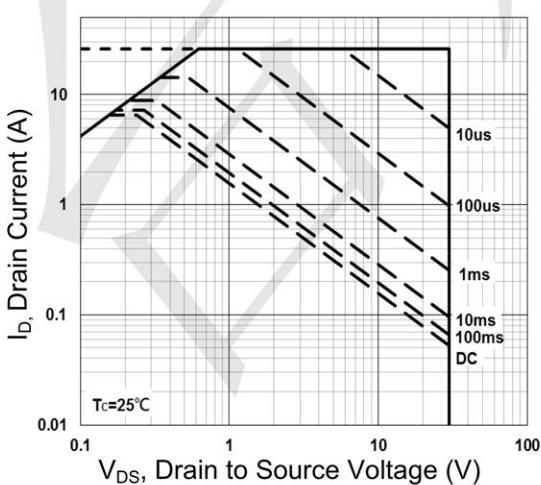
On-Resistance vs. Junction Temperature



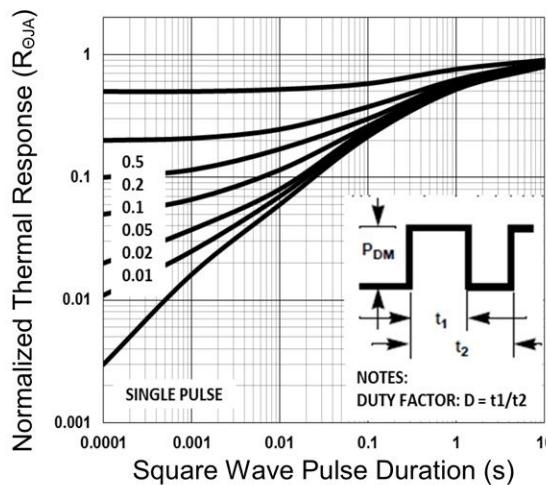
Threshold Voltage vs. Junction Temperature



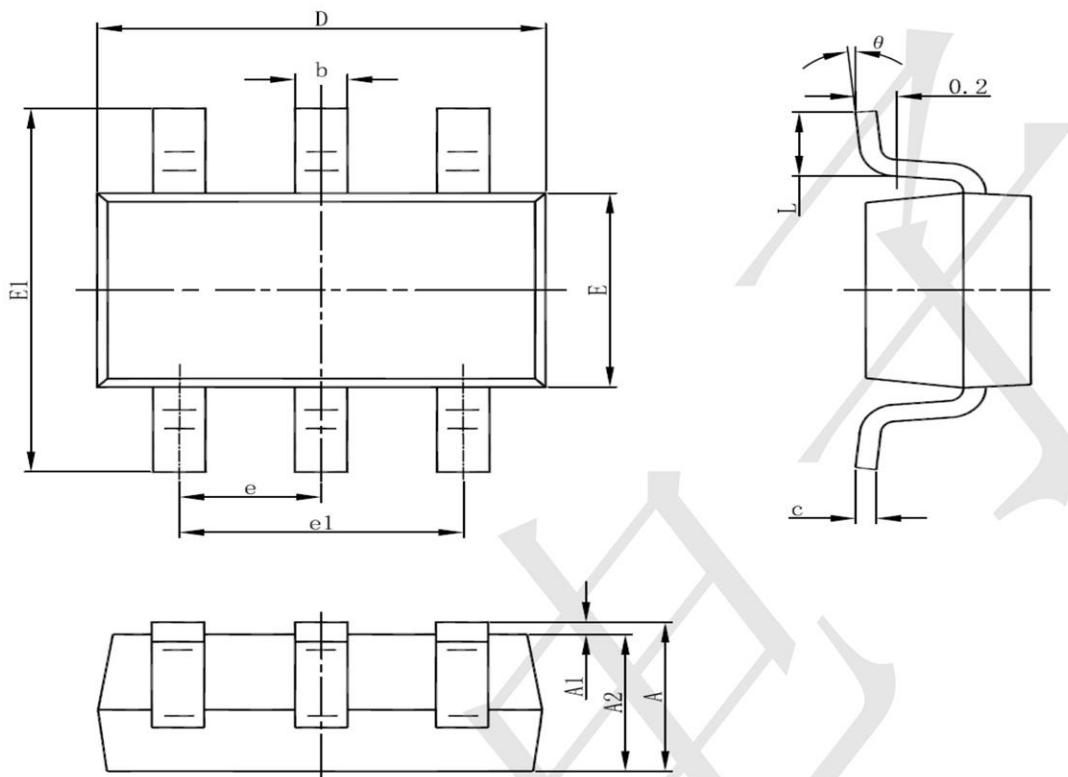
Maximum Safe Operating Area



Normalized Thermal Transient Impedance Curve



SOT23-6 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [TECH PUBLIC](#) manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [NTNS3A92PZT5G](#) [IRFD120](#) [IRFF430](#) [JANTX2N5237](#) [2N7000](#) [AOD464](#)
[2SK2267\(Q\)](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [SSM6J414TU,LF\(T](#) [751625C](#)
[IPS70R2K0CEAKMA1](#) [BSF024N03LT3 G](#) [PSMN4R2-30MLD](#) [TK31J60W5,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#)
[EFC2J004NUZTDG](#) [FCAB21350L1](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [NTE2384](#) [NTE2969](#) [NTE6400A](#) [DMC2700UDMQ-7](#)
[DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [SSM6P54TU,LF](#) [DMP22D4UFO-7B](#) [IPS60R3K4CEAKMA1](#)
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [IPSA70R950CEAKMA1](#) [IPSA70R2K0CEAKMA1](#) [STU5N65M6](#)
[C3M0021120D](#) [DMN6022SSD-13](#)